NSN 5962-01-120-1246

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-120-1246
Body Length:
Between 0.850 inches and 0.930 inches
Body Width:
Between 0.240 inches and 0.295 inches
Body Height:
Between 0.170 inches and 0.200 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
6625-01-069-7884 13499
Features Provided:
Hermetically sealed and w/disable and high performance and low power
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Ram
Memory Capacity:
Unknown
Test Data Document:
13499-351-8410 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a

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Unit Of Measure:

NSN 5962-01-120-1246

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

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